Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-010-5804

Inclosure Material:
Metal
Overall Length:
7.6 millimeters
Overall Diameter:
2.7 millimeters
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Current Rating Per Characteristic:
250.00 milliamperes repetitive peak forward current
Power Rating Per Characteristic:
400.0 milliwatts small-signal input power, common-collector
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0